

# Gerhard Abstreiter

## List of Publications by Year in descending order

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90  
papers

5,053  
citations

76326

40  
h-index

88630

70  
g-index

91  
all docs

91  
docs citations

91  
times ranked

5039  
citing authors

#	ARTICLE	IF	CITATIONS
1	Optically programmable electron spin memory using semiconductor quantum dots. Nature, 2004, 432, 81-84.	27.8	858
2	Coupled Quantum Dots Fabricated by Cleaved Edge Overgrowth: From Artificial Atoms to Molecules. Science, 1997, 278, 1792-1795.	12.6	265
3	Lasing from individual GaAs-AlGaAs core-shell nanowires up to room temperature. Nature Communications, 2013, 4, 2931.	12.8	207
4	Dynamic Electrical Switching of DNA Layers on a Metal Surface. Nano Letters, 2004, 4, 2441-2445.	9.1	161
5	Prismatic Quantum Heterostructures Synthesized on Molecular-Beam Epitaxy GaAs Nanowires. Small, 2008, 4, 899-903.	10.0	142
6	Inelastic Light Scattering from a Quasi-Two-Dimensional Electron System in GaAs-AlxGa1-xAs Heterojunctions. Physical Review Letters, 1979, 42, 1308-1311.	7.8	135
7	Light scattering by free carrier excitations in semiconductors. Topics in Applied Physics, 1984, , 5-150.	0.8	135
8	Switchable DNA interfaces for the highly sensitive detection of label-free DNA targets. Proceedings of the National Academy of Sciences of the United States of America, 2007, 104, 17364-17369.	7.1	123
9	Localization of Fractionally Charged Quasi-Particles. Science, 2004, 305, 980-983.	12.6	120
10	Direct Observation of a Noncatalytic Growth Regime for GaAs Nanowires. Nano Letters, 2011, 11, 3848-3854.	9.1	119
11	Spontaneous Alloy Composition Ordering in GaAs-AlGaAs Core-Shell Nanowires. Nano Letters, 2013, 13, 1522-1527.	9.1	116
12	Organophosphonate-Based PNA-Functionalization of Silicon Nanowires for Label-Free DNA Detection. ACS Nano, 2008, 2, 1653-1660.	14.6	104
13	Thermal conductivity of GaAs nanowires studied by micro-Raman spectroscopy combined with laser heating. Applied Physics Letters, 2010, 97, .	3.3	96
14	Crystal Structure Transfer in Core/Shell Nanowires. Nano Letters, 2011, 11, 1690-1694.	9.1	93
15	Structural Properties of Oligonucleotide Monolayers on Gold Surfaces Probed by Fluorescence Investigations. Langmuir, 2004, 20, 10086-10092.	3.5	91
16	Long range epitaxial growth of prismatic heterostructures on the facets of catalyst-free GaAs nanowires. Journal of Materials Chemistry, 2009, 19, 840.	6.7	88
17	Recent advances in exciton-based quantum information processing in quantum dot nanostructures. New Journal of Physics, 2005, 7, 184-184.	2.9	87
18	Electrical manipulation of oligonucleotides grafted to charged surfaces. Organic and Biomolecular Chemistry, 2006, 4, 3448.	2.8	78

#	ARTICLE	IF	CITATIONS
19	Enhanced Luminescence Properties of InAs/InAsP Core/Shell Nanowires. Nano Letters, 2013, 13, 6070-6077.	9.1	73
20	Growth and properties of InGaAs nanowires on silicon. Physica Status Solidi - Rapid Research Letters, 2014, 8, 11-30.	2.4	68
21	Alloy Fluctuations Act as Quantum Dot-like Emitters in GaAs-AlGaAs Core/Shell Nanowires. ACS Nano, 2015, 9, 8335-8343.	14.6	65
22	Dynamic Acoustic Control of Individual Optically Active Quantum Dot-like Emission Centers in Heterostructure Nanowires. Nano Letters, 2014, 14, 2256-2264.	9.1	64
23	Dissimilar Kinetic Behavior of Electrically Manipulated Single- and Double-Stranded DNA Tethered to a Gold Surface. Biophysical Journal, 2006, 90, 3666-3671.	0.5	61
24	Direct Measurements of Fermi Level Pinning at the Surface of Intrinsically n-Type InGaAs Nanowires. Nano Letters, 2016, 16, 5135-5142.	9.1	60
25	Directional and Dynamic Modulation of the Optical Emission of an Individual GaAs Nanowire Using Surface Acoustic Waves. Nano Letters, 2011, 11, 1512-1517.	9.1	56
26	High Mobility One- and Two-Dimensional Electron Systems in Nanowire-Based Quantum Heterostructures. Nano Letters, 2013, 13, 6189-6196.	9.1	56
27	PNA-PEG Modified Silicon Platforms as Functional Bio-Interfaces for Applications in DNA Microarrays and Biosensors. Biomacromolecules, 2009, 10, 489-496.	5.4	50
28	Tunable Quantum Confinement in Ultrathin, Optically Active Semiconductor Nanowires Via Reverse-Reaction Growth. Advanced Materials, 2015, 27, 2195-2202.	21.0	50
29	GaAs/AlGaAs core/shell nanowire lasers on silicon: invited review. Semiconductor Science and Technology, 2017, 32, 053001.	2.0	48
30	Crystal Phase Quantum Dots in the Ultrathin Core of GaAs/AlGaAs Core/Shell Nanowires. Nano Letters, 2015, 15, 7544-7551.	9.1	47
31	Detection and Size Analysis of Proteins with Switchable DNA Layers. Nano Letters, 2009, 9, 1290-1295.	9.1	46
32	Role of microstructure on optical properties in high-uniformity In <sub>1-x</sub> Ga <sub>x</sub> As nanowire arrays: Evidence of a wider wurtzite band gap. Physical Review B, 2013, 87, .	3.2	46
33	Lattice-Matched InGaAs/InAlAs Core/Shell Nanowires with Improved Luminescence and Photoresponse Properties. Nano Letters, 2015, 15, 3533-3540.	9.1	46
34	Electrochemical passivation of gallium arsenide surface with organic self-assembled monolayers in aqueous electrolytes. Applied Physics Letters, 2000, 76, 3313-3315.	3.3	45
35	Observation of electrostatically released DNA from gold electrodes with controlled threshold voltages. Journal of Chemical Physics, 2004, 120, 5501-5504.	3.0	44
36	Size, composition, and doping effects on In(Ga)As nanowire/Si tunnel diodes probed by conductive atomic force microscopy. Applied Physics Letters, 2012, 101, 233102.	3.3	43

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37	Pressure Tuning of the Optical Properties of GaAs Nanowires. ACS Nano, 2012, 6, 3284-3291.	14.6	43
38	Progress towards single spin optoelectronics using quantum dot nanostructures. Solid State Communications, 2005, 135, 591-601.	1.9	42
39	Controlling the surface density of DNA on gold by electrically induced desorption. Biosensors and Bioelectronics, 2007, 23, 326-331.	10.1	42
40	Growth mechanisms and optical properties of GaAs-based semiconductor microstructures by selective area epitaxy. Journal of Crystal Growth, 2008, 310, 1049-1056.	1.5	42
41	Nonlinear ground-state absorption observed in a single quantum dot. Applied Physics Letters, 2001, 79, 2808-2810.	3.3	38
42	Silicon-on-Insulator Based Thin-Film Resistor for Chemical and Biological Sensor Applications. ChemPhysChem, 2003, 4, 1104-1106.	2.1	36
43	Enhancement of photoluminescence from near-surface quantum dots by suppression of surface state density. Physical Chemistry Chemical Physics, 2002, 4, 785-790.	2.8	35
44	Time-Resolved Photoinduced Thermoelectric and Transport Currents in GaAs Nanowires. Nano Letters, 2012, 12, 2337-2341.	9.1	33
45	$E_{1(A)}$ Electronic Band Gap in Wurtzite InAs Nanowires Studied by Resonant Raman Scattering. Nano Letters, 2013, 13, 3011-3016.	9.1	32
46	Complete thermoelectric benchmarking of individual InSb nanowires using combined micro-Raman and electric transport analysis. Nano Research, 2015, 8, 4048-4060.	10.4	32
47	Spectroscopy of Free Carrier Excitations in Semiconductor Quantum Wells. , 1989, , 153-211.		31
48	Band gap of strain-symmetrized, short-period Si/Ge superlattices. Physical Review B, 1992, 46, 12857-12860.	3.2	31
49	Probing the trapping and thermal activation dynamics of excitons at single twin defects in GaAs-AlGaAs core-shell nanowires. New Journal of Physics, 2013, 15, 113032.	2.9	30
50	Microscopic manifestation of the spin phase transition at filling factor $2/3$ . Nature Physics, 2007, 3, 392-396.	16.7	29
51	Free standing modulation doped core-shell GaAs/AlGaAs hetero-nanowires. Physica Status Solidi - Rapid Research Letters, 2011, 5, 353-355.	2.4	29
52	Excessive Counterion Condensation on Immobilized ssDNA in Solutions of High Ionic Strength. Biophysical Journal, 2003, 85, 3858-3864.	0.5	28
53	Room Temperature Nanoimprint Lithography Using Molds Fabricated by Molecular Beam Epitaxy. IEEE Nanotechnology Magazine, 2008, 7, 363-370.	2.0	27
54	Ultrafast photocurrents and THz generation in single InAs-nanowires. Annalen Der Physik, 2013, 525, 180-188.	2.4	27

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55	Molecular Architecture: Construction of Self-Assembled Organophosphonate Duplexes and Their Electrochemical Characterization. <i>Langmuir</i> , 2012, 28, 7889-7896.	3.5	26
56	Photocurrents in a Single InAs Nanowire/Silicon Heterojunction. <i>ACS Nano</i> , 2015, 9, 9849-9858.	14.6	26
57	The Native Material Limit of Electron and Hole Mobilities in Semiconductor Nanowires. <i>ACS Nano</i> , 2016, 10, 4942-4953.	14.6	26
58	Planar Nanogap Electrodes by Direct Nanotransfer Printing. <i>Small</i> , 2009, 5, 579-582.	10.0	25
59	Electronic properties of the two-dimensional system at GaAs/Al <sub>x</sub> Ga <sub>1-x</sub> As interfaces. <i>Surface Science</i> , 1980, 98, 117-125.	1.9	23
60	Local structure of uncapped and Si-capped Ge/Si(100) self-assembled quantum dots. <i>Applied Physics Letters</i> , 2001, 78, 451-453.	3.3	23
61	Physics and perspectives of Si/Ge heterostructures and superlattices. <i>Physica Scripta</i> , 1993, T49A, 42-45.	2.5	22
62	Multiple Nanowire Species Synthesized on a Single Chip by Selectively Addressable Horizontal Nanochannels. <i>Nano Letters</i> , 2010, 10, 1341-1346.	9.1	22
63	Radio frequency occupancy state control of a single nanowire quantum dot. <i>Journal Physics D: Applied Physics</i> , 2014, 47, 394011.	2.8	22
64	Quantum Confinement-Enhanced Thermoelectric Properties in Modulation-Doped GaAs/AlGaAs Core-Shell Nanowires. <i>Advanced Materials</i> , 2020, 32, e1905458.	21.0	19
65	Local structure of Ge quantum dots self-assembled on Si(100) probed by x-ray absorption fine-structure spectroscopy. <i>Physical Review B</i> , 2002, 66, .	3.2	18
66	Quantum Transport and Sub-Band Structure of Modulation-Doped GaAs/AlAs Core-Superlattice Nanowires. <i>Nano Letters</i> , 2017, 17, 4886-4893.	9.1	18
67	Suppression of alloy fluctuations in GaAs-AlGaAs core-shell nanowires. <i>Applied Physics Letters</i> , 2016, 109, .	3.3	17
68	Controlled synthesis of InAs wires, dot and twin-dot array configurations by cleaved edge overgrowth. <i>Nanotechnology</i> , 2008, 19, 045303.	2.6	15
69	Breakdown of Corner States and Carrier Localization by Monolayer Fluctuations in Radial Nanowire Quantum Wells. <i>Nano Letters</i> , 2019, 19, 3336-3343.	9.1	14
70	Coherent and incoherent properties of single quantum dot photodiodes. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2003, 16, 59-67.	2.7	12
71	Microstructured horizontal alumina pore arrays as growth templates for large area few and single nanowire devices. <i>Physica Status Solidi - Rapid Research Letters</i> , 2008, 2, 59-61.	2.4	12
72	Microscopic nature of crystal phase quantum dots in ultrathin GaAs nanowires by nanoscale luminescence characterization. <i>New Journal of Physics</i> , 2016, 18, 063009.	2.9	12

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73	Silicon/germanium quantum structures. Solid State Communications, 1994, 92, 5-10.	1.9	11
74	pH Sensitivity of Gallium Arsenide (GaAs) Electrodes Functionalized with Methylmercaptobiphenyl Monolayers. Journal of Physical Chemistry C, 2007, 111, 12414-12419.	3.1	11
75	Confinement effects and polarization dependence of luminescence from monolayer-thick Ge quantum wells. Physical Review B, 1996, 54, 1922-1927.	3.2	10
76	Valence Band Splitting in Wurtzite InGaAs Nanoneedles Studied by Photoluminescence Excitation Spectroscopy. ACS Nano, 2014, 8, 11440-11446.	14.6	10
77	Advances in Nanoimprint Lithography. , 2007, , .		9
78	Technology Assessment of a Novel High-Yield Lithographic Technique for Sub-15-nm Direct Nanotransfer Printing of Nanogap Electrodes. IEEE Nanotechnology Magazine, 2009, 8, 662-670.	2.0	9
79	Luminescence and Inelastic Light Scattering in GaAs Doping Superlattices. Springer Series in Solid-state Sciences, 1984, , 232-239.	0.3	7
80	Inelastic light scattering in semiconductor heterostructures. , 1984, , 291-309.		6
81	Light scattering in novel layered semiconductor structures. , 1986, , 41-53.		6
82	Electronic properties of Si/SiGe/Ge heterostructures. Physica Scripta, 1996, T68, 68-71.	2.5	6
83	Pressure dependence of Raman spectrum in InAs nanowires. Journal of Physics Condensed Matter, 2014, 26, 235301.	1.8	6
84	Cleaved-edge-overgrowth nanogap electrodes. Nanotechnology, 2011, 22, 065301.	2.6	5
85	Surface-directed molecular assembly of pentacene on aromatic organophosphonate self-assembled monolayers explored by polarized Raman spectroscopy. Journal of Raman Spectroscopy, 2017, 48, 235-242.	2.5	5
86	Chapter 2 Band Gaps and Light Emission in Si/SiGe Atomic Layer Structures. Semiconductors and Semimetals, 1997, 49, 37-76.	0.7	4
87	All optical preparation, storage, and readout of a single spin in an individual quantum dot. Proceedings of SPIE, 2012, , .	0.8	2
88	The origin to various PL-bands in Si/Ge strain-symmetrized superlattices. Microelectronic Engineering, 1998, 43-44, 165-170.	2.4	0
89	Raman Spectroscopy for the Study of Semiconductor Heterostructures and Superlattices. NATO ASI Series Series B: Physics, 1987, , 301-315.	0.2	0
90	Raman Scattering at Interfaces. NATO ASI Series Series B: Physics, 1987, , 269-278.	0.2	0